



# **High Frequency Amp Applications**

### **Applications**

· Ideally suited for use in FM RF amplifiers, mixers, oscillators, converters, and IF amplifiers.

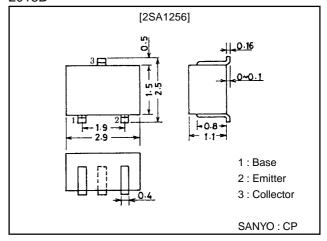
### **Features**

- $\cdot$  High  $f_T$  (230MHz typ), and small Cre (1.1pF typ).
- · Small NF (2.5dB typ).

## **Package Dimensions**

unit:mm

2018B



### **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		-30	V
Collector-to-Emitter Voltage	VCEO		-20	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		-5	V
Collector Current	IC		-30	mA
Collector Dissipation	PC		150	W
Junction Temperature	Tj		125	°C
Storage Temperature	Tstg		-55 to +125	°C

#### Electrical Characteristics at Ta = 25°C

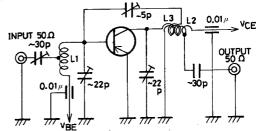
Parameter	Cumbal	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =(-)10V, I <sub>E</sub> =0			-0.1	μΑ
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =(-)4V, I <sub>C</sub> =0			-0.1	μΑ
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =(-)6V, I <sub>C</sub> =(-)1mA	60*		270*	
Gain-Bandwidth Product	fT	V <sub>CE</sub> =(-)6V, I <sub>C</sub> =(-)1mA	150	230		MHz
Reverse Transfer Capacitace	Cre	V <sub>CB</sub> =-6V, f=1MHz		1.1	1.7	pF
Base-to-Collector Time Constant	r <sub>bb</sub> ', Cc	V <sub>CE</sub> =-6V, I <sub>C</sub> =-1mA, f=31.9MHz		11	20	ps
Noise Figure	NF	V <sub>CE</sub> =-6V, I <sub>C</sub> =-1mA, f=100MHz		2.5		dB
Voltage Gain	PG	V <sub>CE</sub> =-6V, I <sub>C</sub> =-1mA, f=100MHz		22		dB

 $\ast$  : The 2SA1256 is classified by 1mA  $h_{FE}$  as follows :

60 E3 120 90 E4 180 135 E5 180

Note: Marking: E h<sub>FE</sub> rank: 3, 4, 5

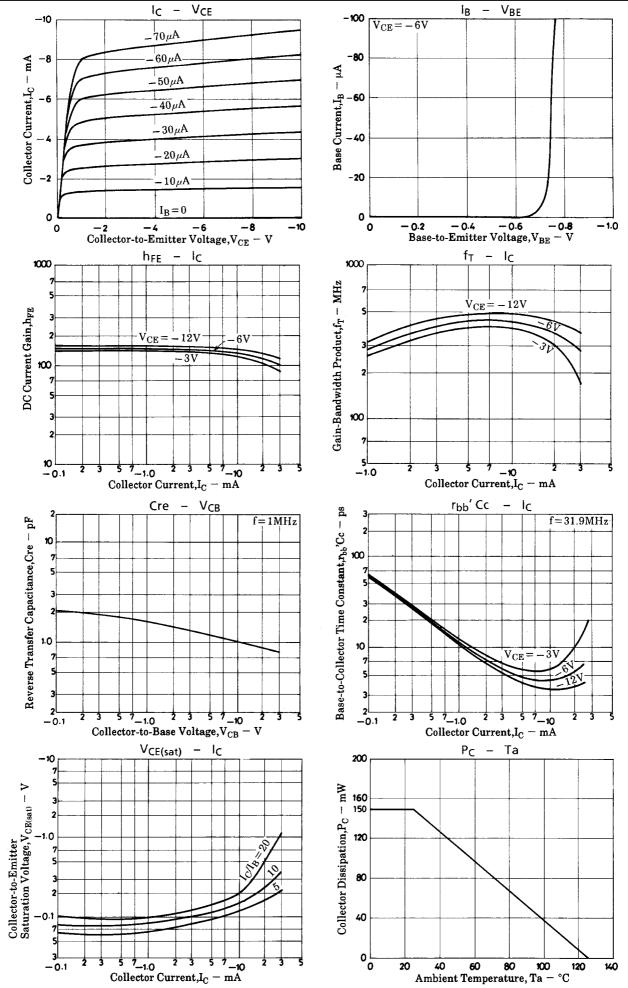
#### **NF, PG Test Circuit**

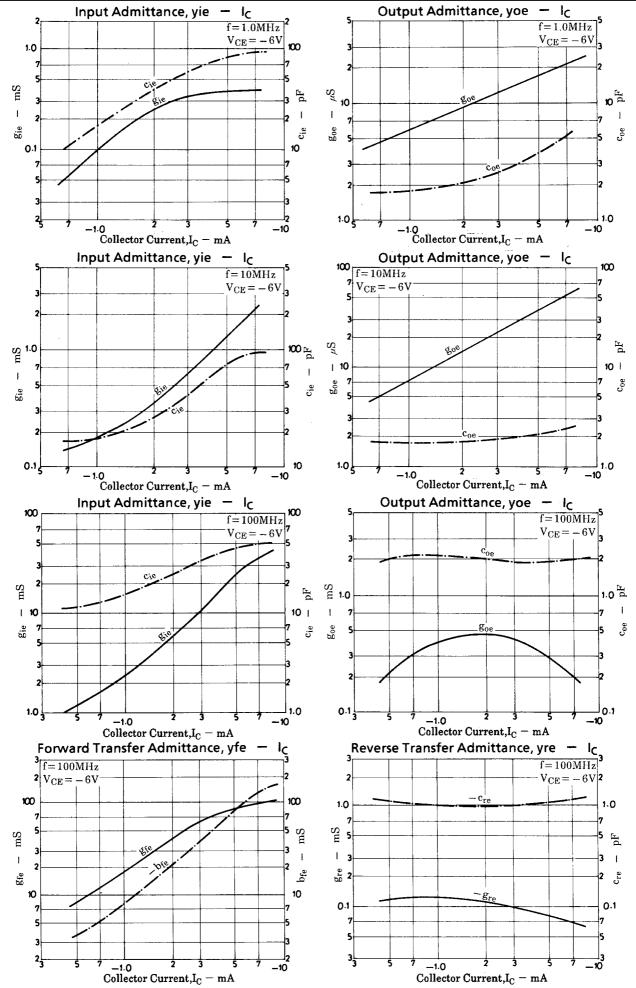


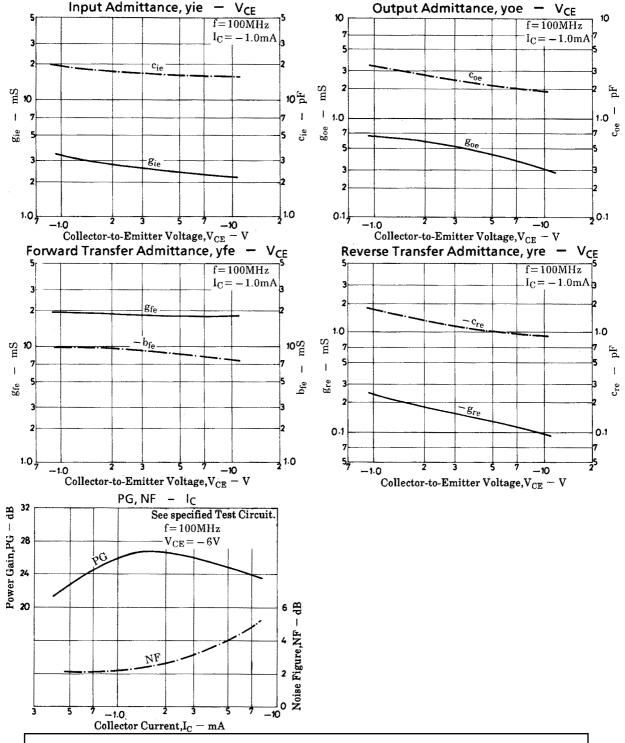
L1 : 1mmø plated wire 10mmø 5T, tap : 2T from  $V_{BE}$  side L2 : 1mmø plated wire 10mmø 7T, tap : 1T from  $V_{CE}$  side

L3: 1mmø enamel wire 10mmø 3T

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